

SPECIFICATION

TO ALL WHOM IT MAY CONCERN:

BE IT KNOWN THAT WE, YASUHIKO INAGAKI, a citizen of Japan residing at Atsugi-Shi, Kanagawa, Japan and TAKAYUKI MASAKI, a citizen of Japan residing at Atsugi-Shi, Kanagawa, Japan have invented certain new and useful improvements in

POWER SUPPLY CIRCUIT CAPABLE OF EFFICIENTLY SUPPLYING  
A SUPPLY VOLTAGE

of which the following is a specification:-

TITLE OF THE INVENTION

POWER SUPPLY CIRCUIT CAPABLE OF  
EFFICIENTLY SUPPLYING A SUPPLY VOLTAGE

5 BACKGROUND OF THE INVENTION

1. Field of the Invention

The present invention generally relates to power supply circuits, and more particularly, to a power supply circuit that delays and outputs an output voltage with respect to an input voltage.

10 2. Description of the Related Art

Power supply circuits supplying drive power for driving, for example, amplifiers are provided with a delay circuit that delays the rise of the drive power for an amplifier so as to improve ripple rejection characteristics and prevent generation of shock noise at the rise of the power.

15 FIG. 1 is a circuit configuration diagram of an example of conventional power supply circuits.

20 Here, a description will be given by taking an amplifier circuit 1 as an example. The amplifier circuit 1 is constructed by a power supply circuit 11 and an amplifier 12. The power supply circuit 11 is a circuit that generates a drive voltage for supplying the drive voltage to the amplifier 12 based on a supply voltage  $V_{CC}$  that is supplied from a power terminal  $T_V$ . The amplifier 12 amplifies and outputs, from an output terminal  $T_{OUT}$ , an input signal that is input to an input terminal  $T_{IN}$  based on the drive voltage supplied from the power supply circuit 11.

25 The power supply circuit 11 is constructed by a reference voltage generation circuit 21, a delay circuit 22, and an output circuit 23. The reference voltage generation circuit 21 is constructed by a constant-current source 31 and a Zener diode  $D_Z$ . The constant-current source 31

generates a constant current  $I_1$  from the supply voltage  $V_{cc}$  applied to the power terminal  $T_v$ . The constant-current  $I_1$  is supplied to the Zener diode  $D_z$ .

5           The Zener diode  $D_z$  generates a Zener voltage  $V_z$  based on the constant current  $I_1$ . The Zener voltage  $V_z$  is applied to the delay circuit 22. The delay circuit 22 is constructed by a resistance  $R_1$  and a capacitor  $C_1$ . The delay circuit 22 has a time constant  $\tau$  that is determined by the resistance  $R_1$  and the capacitor  $C_1$ . The delay circuit 22 delays the Zener voltage  $V_z$  that is output from the reference voltage generation circuit 21 only for the time constant  $\tau$ , and then supplies the Zener voltage to the output circuit 23. The capacitor  $C_1$  is an external component. One end of the capacitor  $C_1$  is connected to a terminal  $T_c$  and the other end is grounded.

20           The output circuit 23 is constructed by a NPN transistor  $Q_1$ . In the transistor  $Q_1$ , the delayed output of the delay circuit 22 is supplied to the base, the supply voltage  $V_{cc}$  is supplied to the collector from the power terminal  $T_v$ , and the drive voltage for the amplifier 12 is output from the emitter.

25           FIG. 2 is an illustrative drawing for explaining the operation of the conventional power supply circuit. FIG. 2-A indicates the supply voltage  $V_{cc}$ , and FIG. 2-B indicates the base potential and emitter potential of the transistor  $Q_1$ .

30           When the supply voltage  $V_{cc}$  rises at time  $t_0$ , the base potential  $V_B$  and emitter potential  $V_E$  of the transistor  $Q_1$  rise after being delayed by the delay circuit 22. On this occasion, the base potential  $V_B$  of the transistor  $Q_1$  can be expressed by:

$$V_B = V_z - (I_B \times R_1) \dots \text{Equation (1)}$$

where the output voltage of the reference voltage generation circuit 21 is  $V_z$  and the base current of the transistor Q1 is  $I_B$ . The voltage  $(I_B \times R_1)$  is 5 the amount of voltage drop caused by the resistance  $R_1$  of the delay circuit 22.

Further, the emitter potential  $V_E$  of the transistor Q1 can be expressed by:

10 
$$V_E = V_z - (I_B \times R_1) - V_F \dots \text{Equation (2)}$$

where  $V_F$  represents the forward voltage between the base and emitter of the transistor Q1.

15 In the conventional power supply circuit, however, the resistance  $R_1$  of the delay circuit 22 causes voltage drop, and the supply voltage  $V_E$  applied to the amplifier 12 assumes the voltage expressed by Equation (2)

20 On the other hand, regarding electronic circuits and electronic devices, there are demands for IC compatibility, cost reduction, miniaturization, and the like. In order to achieve IC compatibility, cost reduction, miniaturization, and the like, it is necessary to limit the 25 capacitance of the capacitor C1 of the delay circuit 22. In order to obtain a delay time  $\tau$  similar to that in the conventional power supply circuit while limiting the capacitance of the capacitor C1, it is necessary to increase the resistance  $R_1$ .

30 When the resistance  $R_1$  is increased, the second term of Equation (2) is increased. Accordingly, the supply voltage  $V_E$  is decreased. When the supply voltage  $V_E$  is decreased, the 35 amplifier circuit 1 shown in FIG. 1 encounters problems in that the peak magnitude of the amplifier 12 is decreased, for example.

SUMMARY OF THE INVENTION

It is a general object of the present invention to provide an improved and useful power supply circuit in which the above-mentioned problems 5 are eliminated.

It is another and more specific object of the present invention to provide a power supply circuit capable of efficiently supplying a supply voltage while positively reducing noise shock, for 10 example.

In order to achieve the above-mentioned objects, according to one aspect of the present invention, there is provided a power supply circuit for generating a supply voltage based on an input 15 constant voltage and supplying the supply voltage to a load, the power supply circuit including:

a delay circuit delaying the input constant voltage;

20 an output circuit generating the supply voltage from the input constant voltage delayed by the delay circuit and supplying the supply voltage to the load; and

25 a current generation circuit generating a current based on the supply voltage that is generated by the output circuit and supplying the generated current to the output circuit as a drive current.

Also, the current generated by the current generation circuit may be set to a current value to 30 drive the output circuit.

In addition, the delay circuit may include:

35 a resistance serially provided between an input terminal to which the input constant voltage is applied and the output circuit; and

a capacitance element provided between a connection point of the resistance and the output

circuit and a base potential terminal serving as a base potential (GND) and delaying the input constant voltage.

Accordingly, the current generation 5 circuit generates the current in accordance with the supply voltage generated by the output circuit and supplies the generated current to the output circuit as the drive current. Thus, it is possible to supply the drive current to the output circuit 10 without going through the delay circuit.

Accordingly, it is possible to eliminate the influence of attenuation caused by the delay circuit.

Further, when the supply voltage is supplied to a plurality of loads, the delay circuit 15 may be provided for the plurality of loads in common, and the output circuit and the current generation circuit may be provided for each of the plurality of loads.

Accordingly, by providing the plurality of 20 loads with the respective output circuits and current generation circuits, it is possible to eliminate the influence of attenuation caused by the delay circuit with respect to the plurality of loads.

Other objects, features and advantages of 25 the present invention will become more apparent from the following detailed description when read in conjunction with the following drawings.

#### BRIEF DESCRIPTION OF THE DRAWINGS

30 FIG. 1 is a circuit configuration diagram of a conventional power supply circuit;

FIG. 2 is an illustrative drawing for explaining the operation of the conventional power supply circuit;

35 FIG. 3 is a circuit configuration diagram of one embodiment of the present invention;

FIG. 4 is an illustrative drawing for

explaining the operation of the embodiment of the present invention; and

FIG. 5 is a circuit configuration diagram of another embodiment of the present invention.

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DETAILED DESCRIPTION OF THE PREFERRED EMBODIMENTS

FIG. 3 is a circuit configuration diagram of one embodiment of the present invention. In FIG. 3, those parts that are the same as those 10 corresponding parts in FIG. 1 are designated by the same reference numerals, and a description thereof will be omitted.

FIG. 3 shows the circuit configuration of an amplifier IC 100 incorporating therein a power 15 supply circuit 111 of this embodiment. The amplifier IC 100 is constructed by the power supply circuit 111 and the amplifier 12. The power supply circuit 111 of this embodiment includes a current generation circuit 124 in addition to the 20 conventional power supply circuit 11 shown in FIG. 1.

The current generation circuit 124 is constructed by a NPN transistor Q2 and PNP transistors Q3 and Q4. The transistor Q2 is connected between the power terminal  $T_v$  and the 25 output circuit 23 and driven when the transistor Q1, constructing the output circuit 23, is driven.

The transistors Q3 and Q4 construct a current mirror circuit, which outputs a current (hereinafter referred to as a "collector current") 30  $I_{c3}$  corresponding to the base current of the transistor Q2 from the collector of the transistor Q3. The collector current  $I_{c3}$  output from the collector of the transistor Q3 is supplied to the connection point of the delay circuit 22 and the 35 base of the transistor Q1.

The collector current  $I_{c3}$  of the transistor Q3 is set to a desired current  $I_B$  that is

to be supplied to the base of the transistor Q1. The collector current  $I_{C3}$  of the transistor Q3 is set by, for example, the emitter areas of the transistors Q3 and Q4.

5        The current generation circuit 124 is driven in accordance with the operating state of the transistor Q1 that constructs the output circuit 23. On this occasion, the operation of the output circuit 23 is delayed by the delay circuit 22 at the 10 rise of the supply voltage  $V_{CC}$ . Since the current generation circuit 124 is driven in accordance with the operation of the output circuit 23, the operation of the current generation circuit 124 is also delayed by the delay in the operation of the 15 output circuit 23. Hence, shock noise is not generated by driving the current generation circuit 124.

FIG. 4 is an illustrative drawing for explaining the operation of the embodiment of the 20 present invention. FIG. 4-A indicates the supply voltage  $V_{CC}$ , and FIG. 4-B indicates the emitter potential of the transistor Q1.

When the supply voltage  $V_{CC}$  rises at time  $t_0$ , the emitter potential of the transistor Q1 rises 25 after being delayed by the time constant  $\tau$  that is determined by the resistance  $R_1$  and capacitor  $C_1$  of the delay circuit 22.

On this occasion, the base current  $I_B$  of the transistor Q1 is supplied from the current 30 generation circuit 124, and a current does not flow to the resistance  $R_1$ . Consequently, the second term ( $I_B \times R_1$ ) of Equation (2) becomes "0". Thus, the emitter potential  $V_E$  of the transistor Q1 can be expressed by:

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$$V_E = V_Z - V_F \dots \text{Equation (3)}$$

where  $VF$  is the forward voltage between the base and emitter of the transistor  $Q1$ .

In other words, it is possible to increase the voltage that can be applied to the amplifier 12 only for  $(IB \times R1)$ , compared to the conventional technique. Accordingly, it is possible to increase the peak magnitude of the amplifier 12 only for the amount corresponding to  $(IB \times R1)$ .

In addition, the present invention may be applied also to an IC incorporating therein a plurality of the amplifiers 12.

FIG. 5 is a circuit configuration diagram of another embodiment of the present invention. In FIG. 5, those parts that are the same as those corresponding parts in FIG. 3 are designated by the same reference numerals, and a description thereof will be omitted.

An amplifier circuit 201 of this embodiment includes therein a plurality of amplifiers 12-1 through 12-n. The plurality of amplifiers 12-1 through 12-n are provided with respective output circuits 23-1 through 23-n and current generation circuits 124-1 through 124-n.

The current generation circuit 124-1 supplies the base current  $IB$  to the output circuit 23-1. The current generation circuit 124-2 supplies the base current  $IB$  to the output circuit 23-2. Similarly, the current generation circuit 124-n supplies the base current  $IB$  to the output circuit 23-n.

The present invention is not limited to the specifically disclosed embodiments, and variations and modifications may be made without departing from the scope of the present invention.

The present application is based on Japanese priority application No. 2002-277758 filed on September 24, 2002, the entire contents of which

are hereby incorporated by reference.